International **IOR** Rectifier

HEXFRED[™]

Features

- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I_{RRM}
- Very Low Q_{rr}
- · Specified at Operating Conditions

Benefits

- Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- · Reduced Parts Count

Description

International Rectifier's HFA15TB60S is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 8 amps per Leg continuous current, the HFA15TB60S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_{b} portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA15TB60S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

Absolute Maximum Ratings

	Parameter	Max.	Units
V _R	Cathode-to-Anode Voltage	600	V
I _F @ T _C = 100°C	Continuous Forward Current	15	
IFSM	Single Pulse Forward Current	150	A
I _{FRM}	Maximum Repetitive Forward Current	60	1
P _D @ T _C = 25°C	Maximum Power Dissipation	74	w
P _D @ T _C = 100°C	Maximum Power Dissipation	29	1 **
TJ	Operating Junction and	55 to 1450	°C
T _{STG}	Storage Temperature Range	-55 to +150	

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HFA15TB60S

Ultrafast, Soft Recovery Diode

Base

Cathode

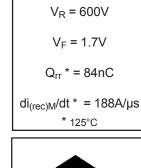
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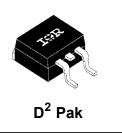
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Anode





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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
V _{BR}	Cathode Anode Breakdown Voltage	600			V	I _R = 100μA	
V _{FM}	Max Forward Voltage		1.3	1.7	V	I _F = 15A	
			1.5	2.0		I _F = 30A See Fig. 1	
			1.2	1.6		I _F = 15A, T _J = 125°C	
I _{RM}	Max Reverse Leakage Current		1.0	10	μA	$V_R = V_R$ Rated See Fig. 2	
			400	1000		T _J = 125°C, V _R = 0.8 x V _R Rated	
CT	Junction Capacitance		25	50	pF	V _R = 200V See Fig. 3	
L _S	Series Inductance		8.0		nH	Measured lead to lead 5mm from package body	

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Test Conditions		
t _{rr}	Reverse Recovery Time		23			I _F = 1.0A, di _f /dt = 200/	õs, V _R = 30V	
t _{rr1}	See Fig. 5		50	60	ns	T _J = 25°C		
t _{rr2}			105	120		T _J = 125°C	I _F = 15A	
I _{RRM1}	Peak Recovery Current		4.5	6.0	A	T _J = 25°C		
I _{RRM2}	See Fig. 6		6.5	10		T _J = 125°C	V _R = 200V	
Q _{rr1}	Reverse Recovery Charge		84	180	nC	T _J = 25°C		
Q _{rr2}	See Fig. 7		241	600		T _J = 125°C	di _f /dt = 200A/µs	
di _{(rec)M} /dt1	Peak Rate of Fall of Recovery Current		188		A/µs	T _J = 25°C		
di _{(rec)M} /dt2	During t _b See Fig. 8		160		μ5	T _J = 125°C		

Thermal - Mechanical Characteristics

	Parameter	Min.	Тур.	Max.	Units
T _{lead} ①	Lead Temperature			300	°C
R _{thJC}	Thermal Resistance, Junction to Case			1.7	K/W
R _{thJA} ②	Thermal Resistance, Junction to Ambient			80	
Wt	Weight		2.0		g
			0.07		(oz)

① 0.063 in. from Case (1.6mm) for 10 sec

② Typical Socket Mount

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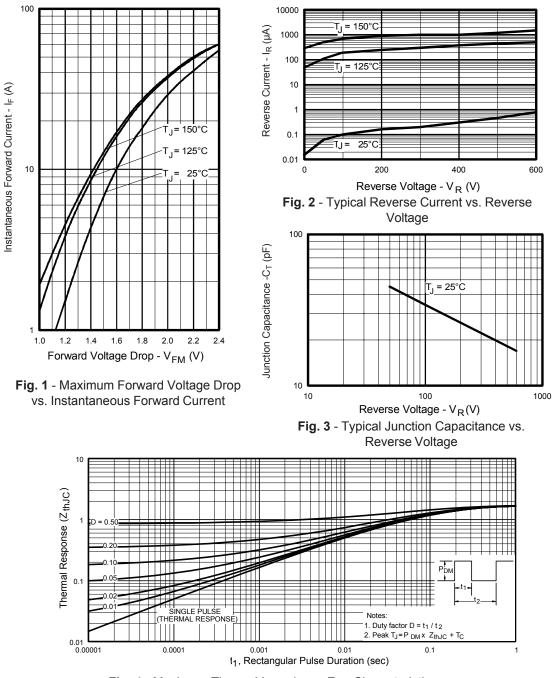


Fig. 4 - Maximum Thermal Impedance Zthjc Characteristics

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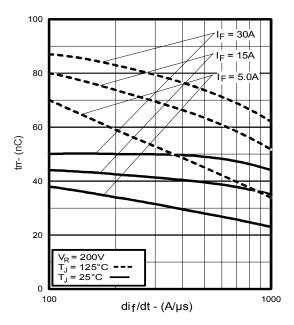


Fig. 5 - Typical Reverse Recovery vs. dif/dt

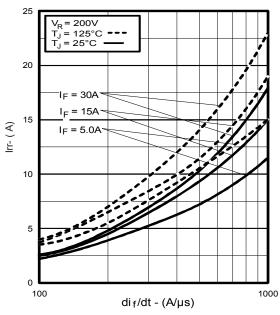


Fig. 6 - Typical Recovery Current vs. dif/dt

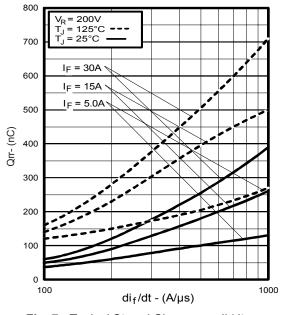
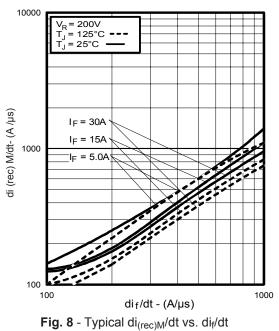


Fig. 7 - Typical Stored Charge vs. dif/dt



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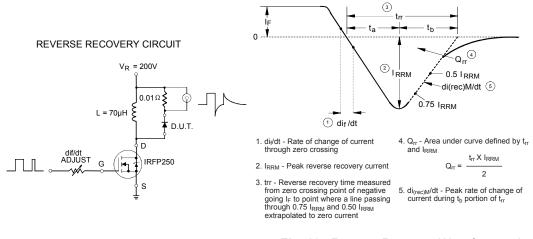
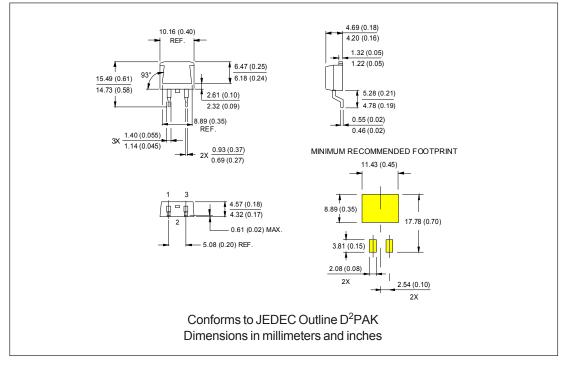


Fig. 9 - Reverse Recovery Parameter Test Circuit

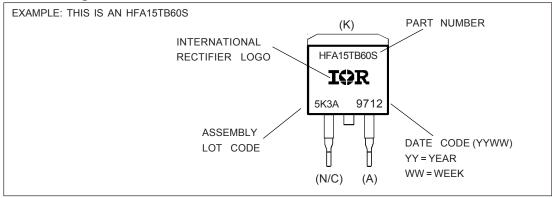


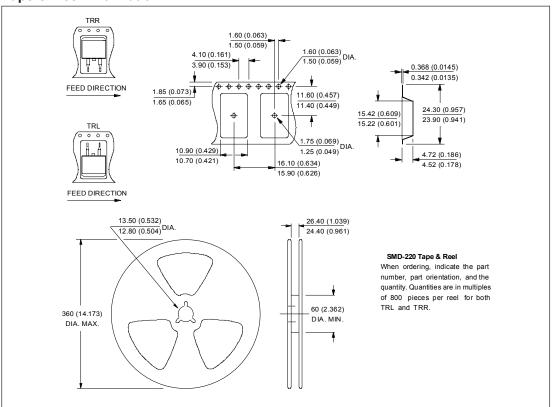
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Outline Table



Part Marking Information





Tape & Reel Information

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level. Qualification Standards can be found on IR's Web site.

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